

Enhancement in photocatalytic water splitting using van der Waals heterostructure materials based on penta-layers

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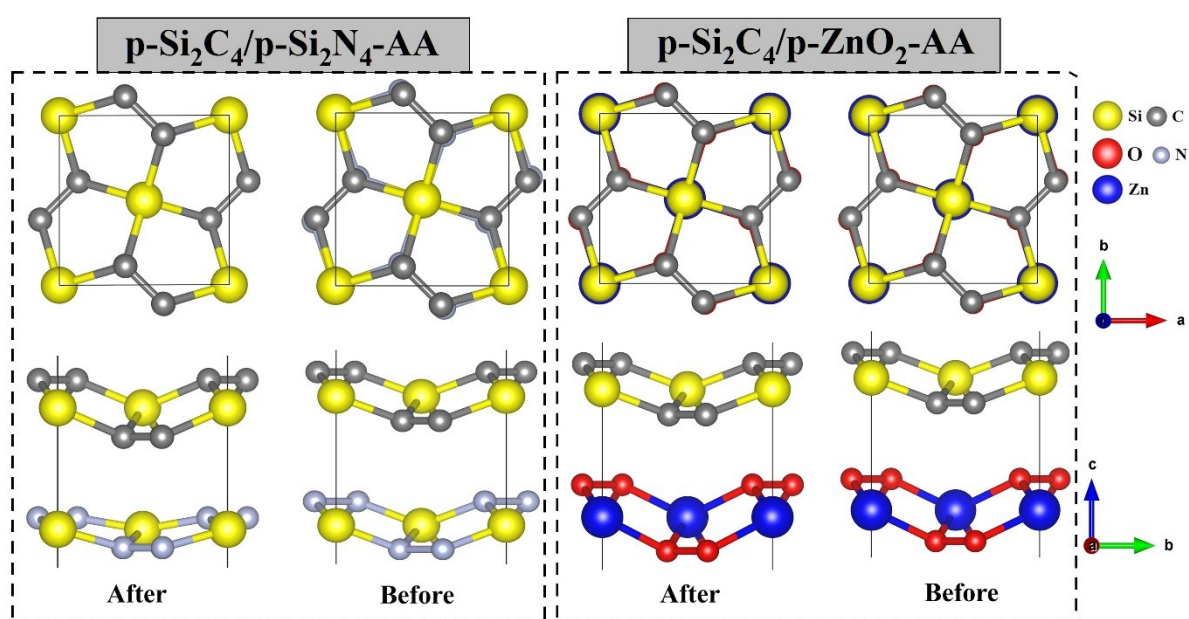


Fig. S1. Top and side views of (left) p-Si₂C₄/p-Si₂N₄, (right) p-Si₂C₄/p-ZnO₂ vdWHs with AA stacking mode after and before structural optimization.

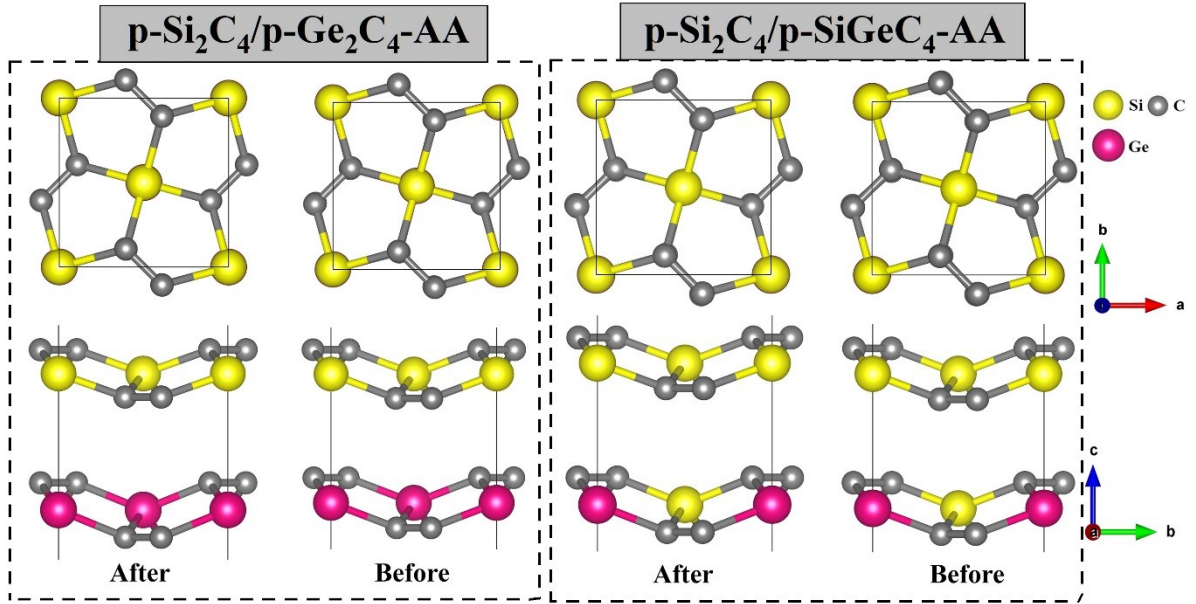


Fig. S2. Top and side views of (left) $p\text{-Si}_2\text{C}_4/p\text{-Ge}_2\text{C}_4$, (right) $p\text{-Si}_2\text{C}_4/p\text{-SiGeC}_4$ *vdWHs* with AA stacking mode after and before structural optimization.

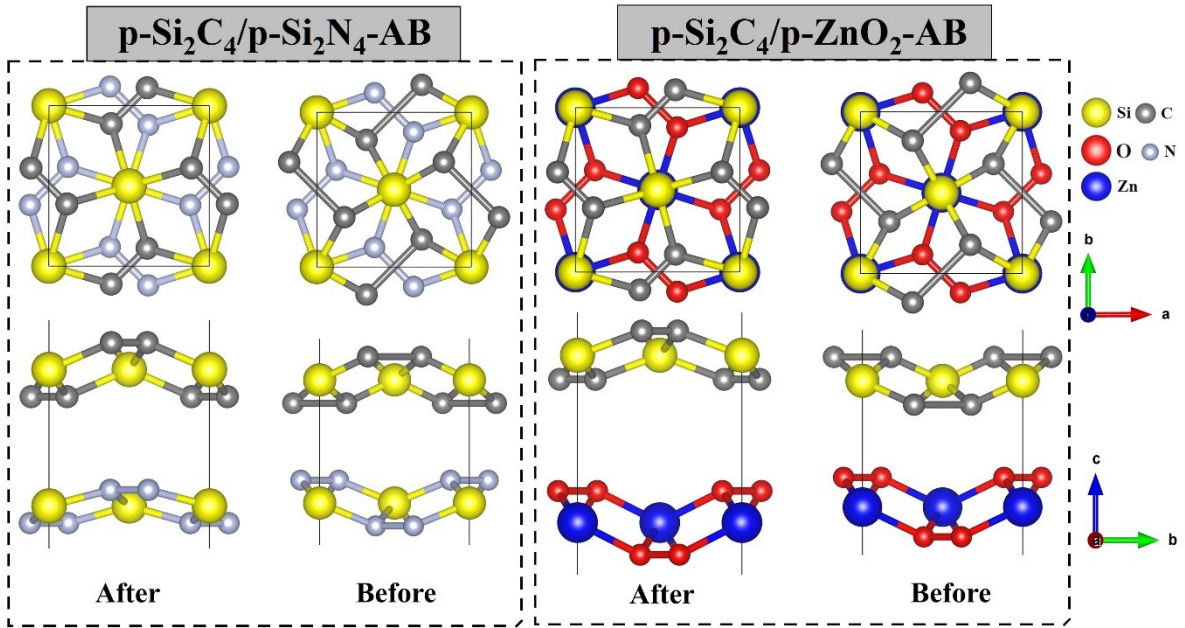


Fig. S3. Top and side views of (left) $p\text{-Si}_2\text{C}_4/p\text{-Si}_2\text{N}_4$, (right) $p\text{-Si}_2\text{C}_4/p\text{-ZnO}_2$ *vdWHs* with AB stacking mode after and before structural optimization.

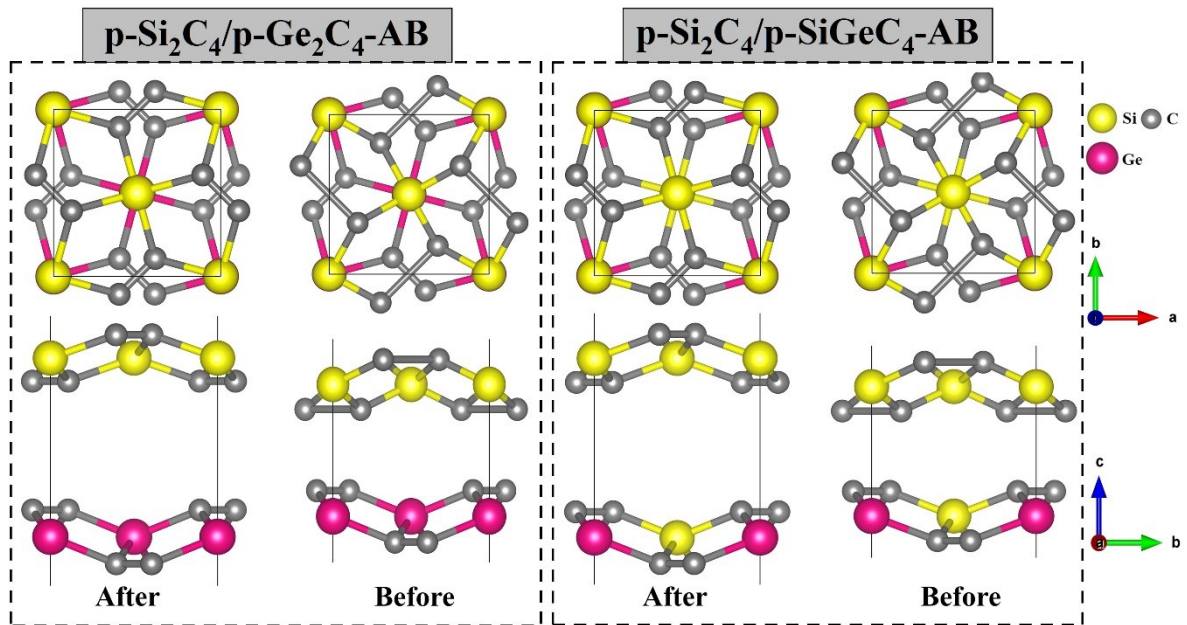


Fig. S4. Top and side views of (left) $p\text{-Si}_2\text{C}_4/p\text{-Ge}_2\text{C}_4$, (right) $p\text{-Si}_2\text{C}_4/p\text{-SiGeC}_4$ vdWHs with AB stacking mode after and before structural optimization.